TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SA970

## Low Noise Audio Amplifier Applications

Unit: mm

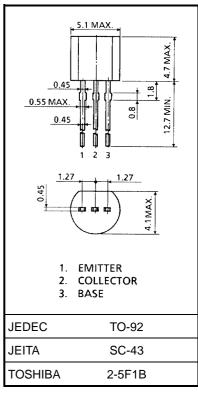
• Low noise: NF = 3dB (typ.)  $R_G$  = 100  $\Omega$ ,  $V_{CE}$  = -6 V,  $I_C$  = -100  $\mu A$ , f = 1 kHz : NF = 0.5dB (typ.)  $R_G$  = 1 k $\Omega$ ,  $V_{CE}$  = -6 V,  $I_C$  = -100  $\mu A$ , f = 1 kHz

• High DC current gain: hFE =  $200 \sim 700$ • High breakdown voltage: VCEO = -120 V

• Low pulse noise. Low 1/f noise

## Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-120	V
Collector-emitter voltage	V <sub>CEO</sub>	-120	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	I <sub>C</sub>	-100	mA
Base current	Ι <sub>Β</sub>	-20	mA
Collector power dissipation	PC	300	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

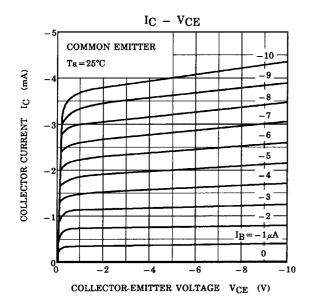


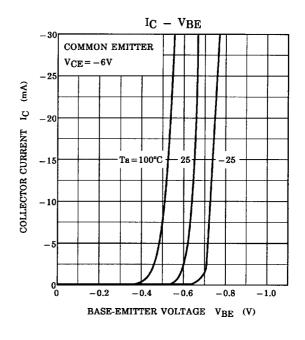
Weight: 0.21 g (typ.)

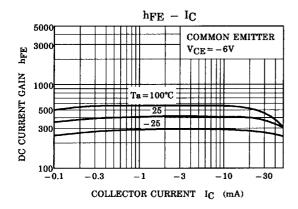
## **Electrical Characteristics (Ta = 25°C)**

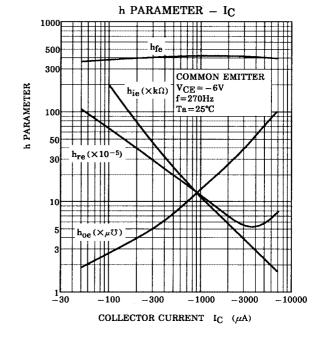
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -120 \text{ V}, I_E = 0$	_	_	-0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-0.1	μΑ
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = -1 \text{ mA}, I_B = 0$	-120	_	_	V
DC current gain	h <sub>FE</sub> (Note)	$V_{CE} = -6 \text{ V}, I_{C} = -2 \text{ mA}$	200	_	700	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$	_	_	-0.3	V
Base-emitter voltage	$V_{BE}$	$V_{CE} = -6 \text{ V}, I_{C} = -2 \text{ mA}$	_	0.65	_	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -6 \text{ V}, I_{C} = -1 \text{ mA}$	_	100	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$	_	4.0	_	pF
Noise figure	NF	$\begin{split} &V_{CE} = -6 \text{ V, I}_{C} = -0.1 \text{ mA, f} = 10 \text{ Hz,} \\ &R_{G} = 10 \text{ k}\Omega \end{split}$	_	_	6	dB
		$\begin{aligned} &V_{CE} = -6 \text{ V, I}_{C} = -0.1 \text{ mA, f} = 1 \text{ kHz,} \\ &R_{G} = 10 \text{ k}\Omega \end{aligned}$		_	2	
		$\begin{aligned} &V_{CE} = -6 \text{ V, I}_{C} = -0.1 \text{ mA, f} = 1 \text{ kHz,} \\ &R_{G} = 100 \Omega \end{aligned}$		3		

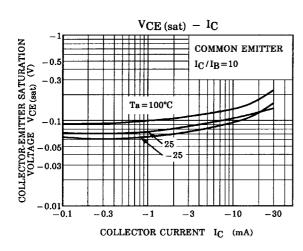
Note: hFE classification GR: 200~400, BL: 350~700



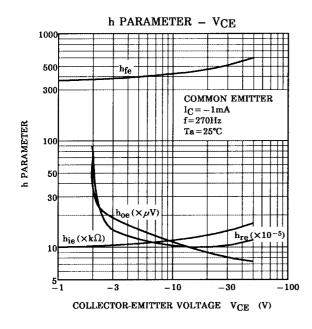


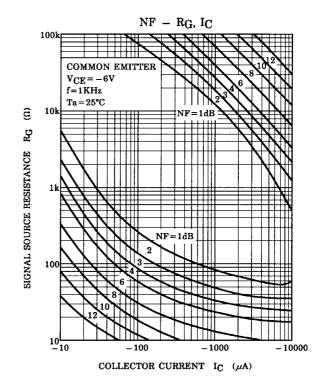


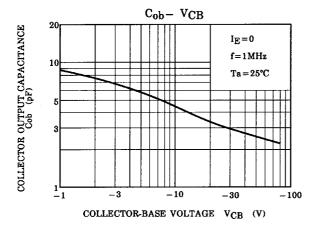


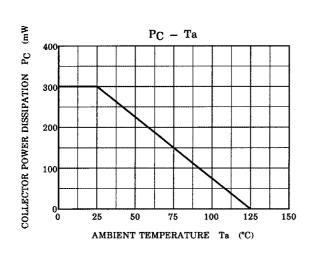


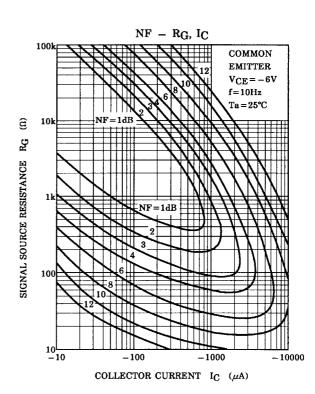
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